NSN 5962-00-529-0425



Memory Microcircuit - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5962-00-529-0425 **Body Length:** 1.250 inches **Body Width:** 0.520 inches **Body Height:** 0.160 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and negative outputs and 3-state output and high speed and programmable and w/decoded output and programmed **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** P-type metal oxide-semiconductor logic **Input Circuit Pattern:** 11 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -0.3 volts power source and 20.0 volts power source **Time Rating Per Chacteristic:** 1000.00 nanoseconds propagation delay time, low to high level output and 1000.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:** 94117-310132 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a

Fiia:

Unit Of Measure:

Demilitarization: Yes - demil/mli